

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

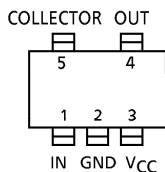
TA4003F

VHF~UHF WIDE BAND AMPLIFIER

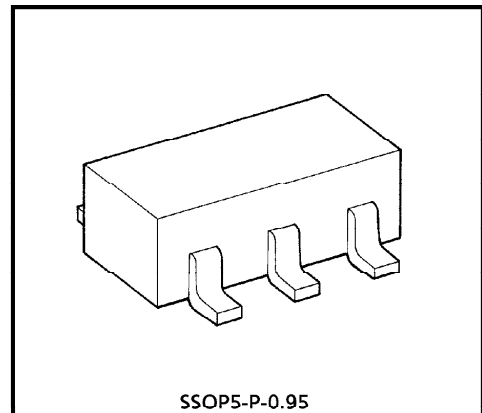
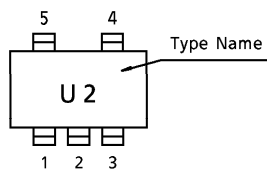
FEATURES

- Band Width 1.5CHz (Typ.) (3dB down, $V_{CC} = 2V$)
- High Gain : $|S_{21}|^2 = 11dB$ (Typ.), ($f = 500MHz$, $V_{CC} = 2V$)
- Operating Supply Voltage : $V_{CC} = 2\sim 3V$
- Low Current Operation : $I_{CC} = 3.5mA$ (Typ.) ($V_{CC} = 2V$)
- Small Package

PIN ASSIGNMENT (TOP VIEW)



Marking



Weight : 0.014g (Typ.)

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	4	V
Total Power Dissipation	P_D^*	300	mW
Operating Temperature	T_{opr}	- 40~85	$^\circ C$
Storage Temperature	T_{stg}	- 55~125	$^\circ C$

* When mounted glass epoxy of $2.5cm^2 \times 1.6t$

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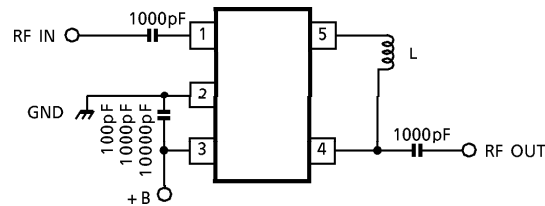
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ELECTRICAL CHARACTERISTICS (Ta = 25°C) (Note 1)

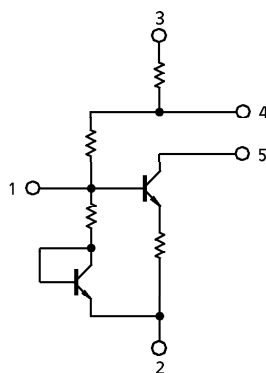
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Circuit Current	I _{CC}	—	V _{CC} = 2V, Non carrier	2.5	3.5	4.5	mA
Insertion Gain	S ₂₁ ²	1	V _{CC} = 2V, f = 500MHz	9	11	14	dB
Band Width	BW	1	V _{CC} = 2V (Note 2)	1.2	1.5	—	GHz
Noise Figure	NF	1	V _{CC} = 2V, f = 500MHz	—	5.2	7	dB
Input Return Loss	S ₁₁ ²	1	V _{CC} = 2V, f = 500MHz	—	-7.5	—	dB
Output Return Loss	S ₂₂ ²	1	V _{CC} = 2V, f = 500MHz	—	-7.5	—	dB
Isolation	S ₁₂ ²	1	V _{CC} = 2V, f = 500MHz	—	-24	—	dB
Maximum Output Level	P _O	1	V _{CC} = 2V, f = 500MHz, Pin = 0dBmW	—	0	—	dBmW

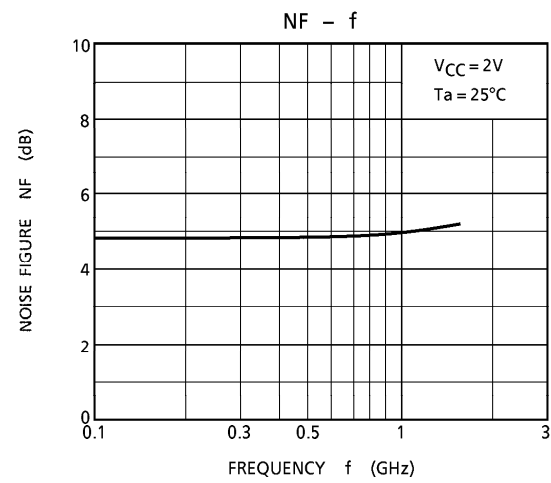
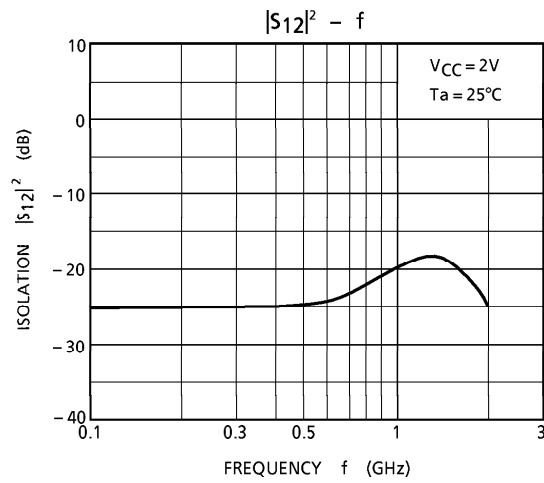
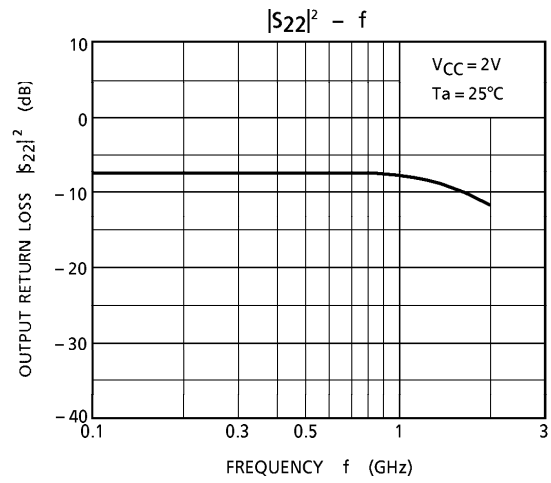
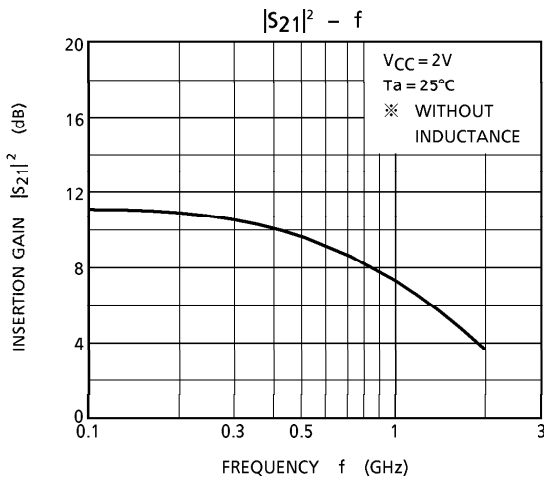
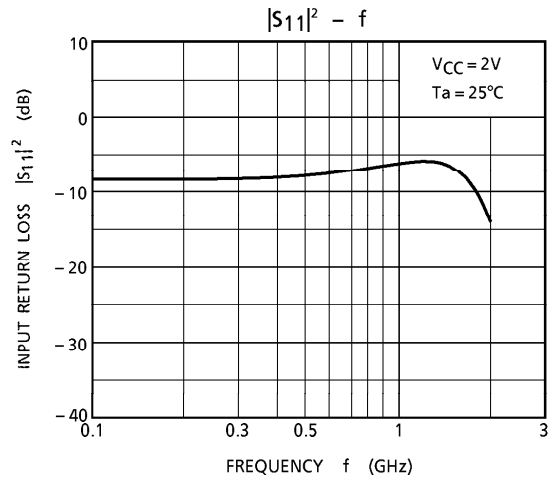
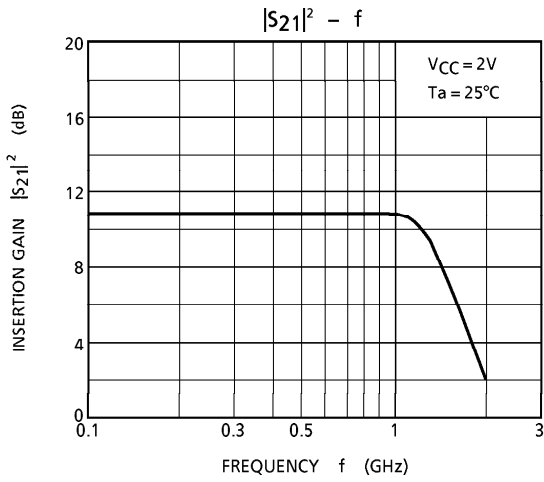
Note 1 : Have use for connect inductance between terminal 4 and 5 8nH at V_{CC} = 2V
 Note 2 : BW is frequency of 3dB down from |S₂₁|² at 500MHz.

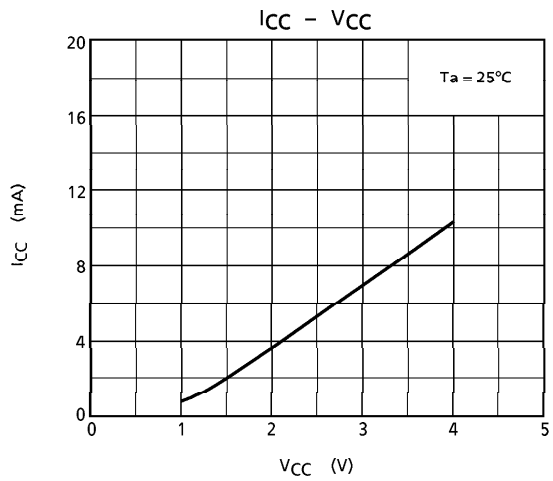
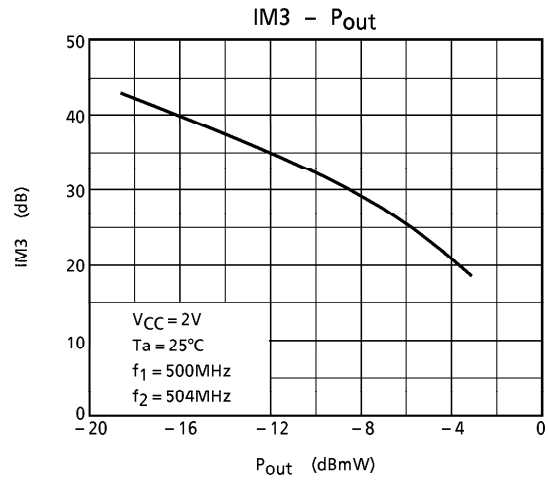
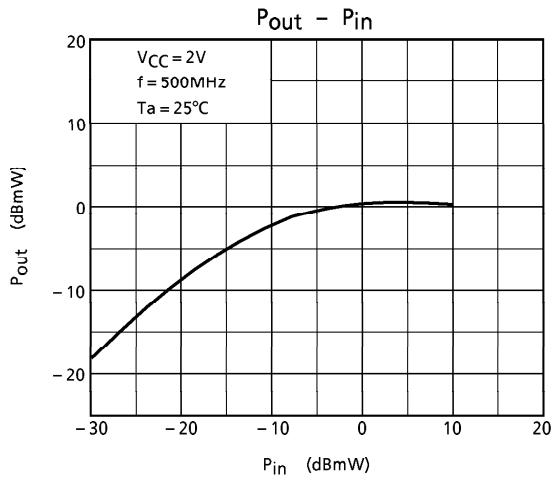
TEST CIRCUIT 1. (TOP VIEW)



EQUIVALENT CIRCUIT

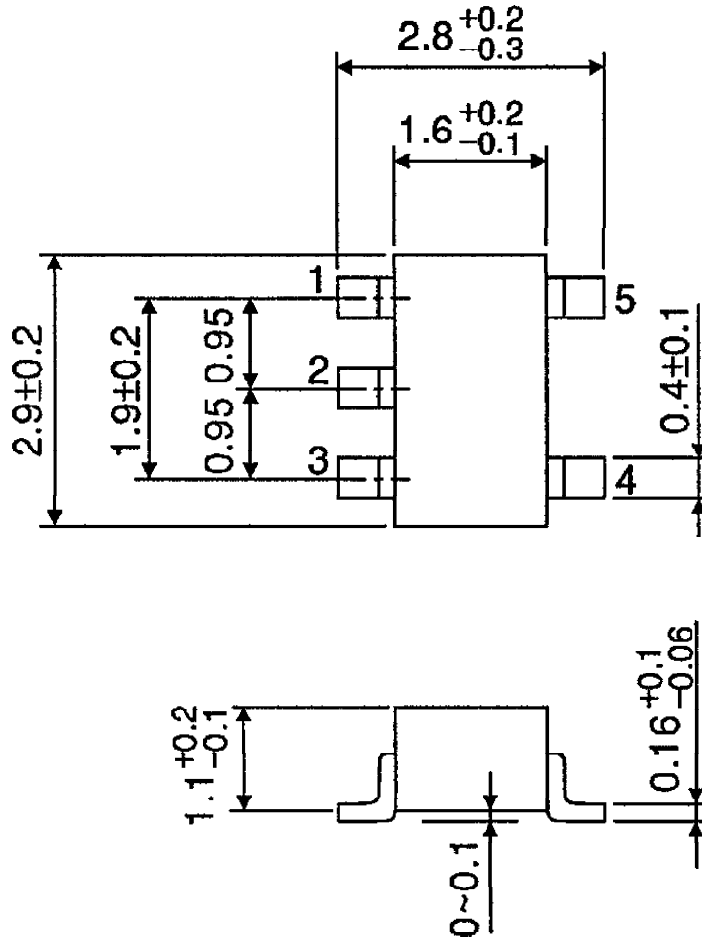






OUTLINE DRAWING
SSOP5-P-0.95

Unit : mm



Weight : 0.014g (Typ.)